

LM160/LM360 High Speed Differential Comparator

Check for Samples: LM160, LM360

FEATURES

- Ensured high speed: 20 ns max
- Tight delay matching on both outputs
- Complementary TTL outputs
- High input impedance
- Low speed variation with overdrive variation
- Fan-out of 4
- Low input offset voltage
- Series 74 TTL compatible

DESCRIPTION

The LM160/LM360 is a very high speed differential input, complementary TTL output voltage comparator with improved characteristics over μΑ760/μΑ760C, for which it is a pin-for-pin replacement. The device has been optimized for greater speed, input impedance and fan-out, and lower input offset voltage. Typically delay varies only 3 ns for overdrive variations of 5 mV to 400 mV.

Complementary outputs having minimum skew are provided. Applications involve high speed analog to digital convertors and zero-crossing detectors in disk file systems.

CONNECTION DIAGRAMS

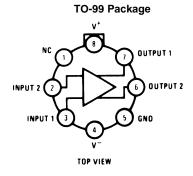


Figure 1. Package Number LMC0008C (1)

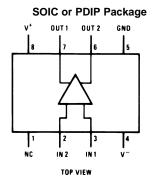


Figure 2. Package Number D0008A or P0008E

(1) Also available in SMD# 5962-8767401



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

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Absolute Maximum Ratings (1) (2)

	0-				
Positive Supply Voltage		+8V			
Negative Supply Voltage		-8V			
Peak Output Current		20 mA			
Differential Input Voltage		±5V			
Input Voltage					
ESD Tolerance (3)	1600V				
Operating Temperature	LM160	−55°C to +125°C			
Range	LM360	0°C to +70°C			
Storage Temperature Range		−65°C to +150°C			
Lead Temperature	(Soldering, 10 sec.)	260°C			
Soldering Information					
PDIP Package	Soldering (10 seconds)	260°C			
SOIC Package	Vapor Phase (60 seconds)	215°C			
	Infrared (15 seconds)	220°C			
See AN-450 "Surface Mount	ing Methods and Their Effect on Product Reliability" for other methods of	soldering surface mount devices.			

The device may be damaged if used beyond the maximum ratings.

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⁽²⁾ (3) Refer to RETS 160X for LM160H, LM160J-14 and LM160J military specifications. Human body model, 1.5 k Ω in series with 100 pF.



Electrical Characteristics

 $(T_{MN} \leq T_A \leq T_{MAX})$

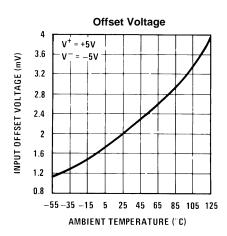
Parameter	Conditions	Min	Тур	Max	Units
Operating Conditions	25.13.115.13		.,,,,		
Supply Voltage V _{CC} ⁺		4.5	5	6.5	V
Supply Voltage V _{CC} ⁻		-4.5	-5	-6.5	V
Input Offset Voltage	R _S ≤ 200Ω		2	5	mV
Input Offset Current	- C		0.5	3	μA
Input Bias Current			5	20	μA
Output Resistance (Either Output)	V _{OUT} = V _{OH}		100		Ω
Response Time	$T_A = 25^{\circ}C$, $V_S = \pm 5V^{(1)}$ (2)		13	25	ns
	$T_A = 25$ °C, $V_S = \pm 5V^{(3)}$ (2)		12	20	ns
	$T_A = 25^{\circ}C, V_S = \pm 5V^{(4)(2)}$		14		ns
Response Time Difference between Outputs					
$(t_{pd} \text{ of } +V_{IN1}) - (t_{pd} \text{ of } -V_{IN2})$	$T_A = 25^{\circ}C^{(1)(2)}$		2		ns
$(t_{pd} \text{ of } +V_{IN2}) - (t_{pd} \text{ of } -V_{IN1})$	$T_A = 25^{\circ}C^{(1)(2)}$		2		ns
$(t_{pd} \text{ of } +V_{IN1}) - (t_{pd} \text{ of } +V_{IN2})$	$T_A = 25^{\circ}C^{(1)(2)}$		2		ns
$(t_{pd} \text{ of } -V_{IN1}) - (t_{pd} \text{ of } -V_{IN2})$	$T_A = 25^{\circ}C^{(1)(2)}$		2		ns
Input Resistance	f = 1 MHz		17		kΩ
Input Capacitance	f = 1 MHz		3		pF
Average Temperature Coefficient of Input Offset Voltage	$R_S = 50\Omega$		8		μV/°C
Average Temperature Coefficient of Input Offset Current			7		nA/°C
Common Mode Input Voltage Range	V _S = ±6.5V	±4	±4.5		V
Differential Input Voltage Range		±5			V
Output High Voltage (Either Output)	$I_{OUT} = -320 \mu A, V_S = \pm 4.5 V$	2.4	3		V
Output Low Voltage (Either Output)	I _{SINK} = 6.4 mA		0.25	0.4	V
Positive Supply Current	$V_S = \pm 6.5 V$		18	32	mA
Negative Supply Current	$V_S = \pm 6.5 V$		-9	-16	mA

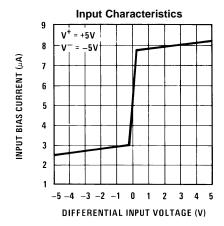
 ⁽¹⁾ Response time measured from the 50% point of a 30 mVp-p 10 MHz sinusoidal input to the 50% point of the output.
 (2) Measurements are made in AC Test Circuit, Fanout = 1

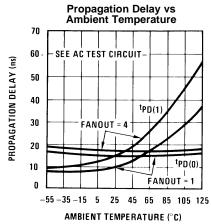
Submit Documentation Feedback Product Folder Links: LM160 LM360

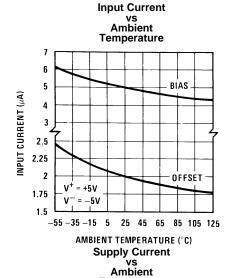
⁽³⁾ (4) Response time measured from the 50% point of a 2 Vp-p 10 MHz sinusoidal input to the 50% point of the output. Response time measured from the start of a 100 mV input step with 5 mV overdrive to the time when the output crosses the logic threshold.

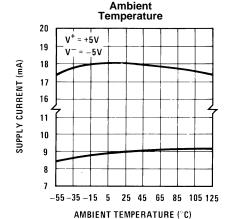
Typical Performance Characteristics

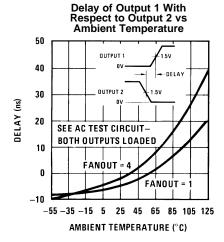






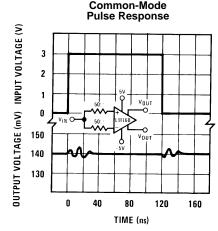








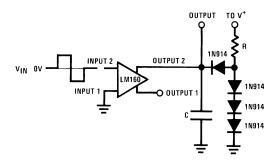
Typical Performance Characteristics (continued) Common-Mode Pulse Response



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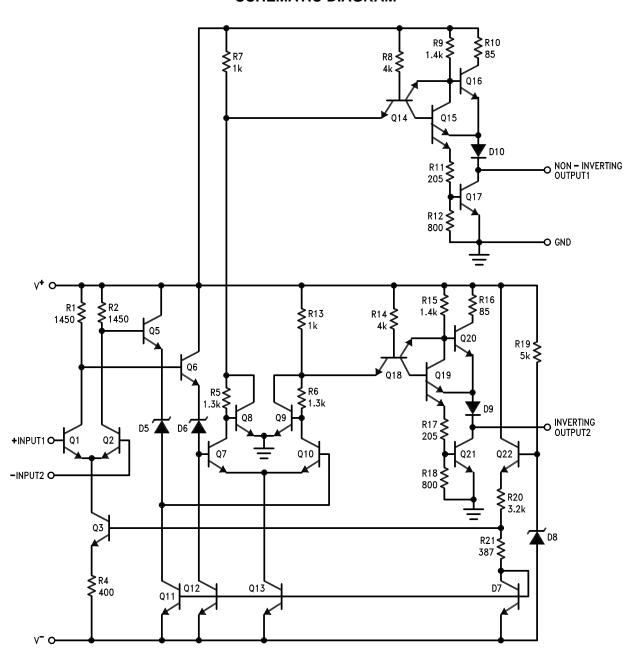
AC TEST CIRCUIT



 V_{IN} =±50 mV FANOUT=1 FANOUT=4 V^{+} =+5V R=2.4k R=630 Ω V=-5V C=15 pF C=30 pF



SCHEMATIC DIAGRAM



SNOSBJ4C -MAY 1999-REVISED MARCH 2013



REVISION HISTORY

Ch	nanges from Revision B (March 2013) to Revision C	Page
•	Changed layout of National Data Sheet to TI format	

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing		Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LM360M	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	0 to 70	LM 360M	
LM360M/NOPB	ACTIVE	SOIC	D	8	95	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM 360M	Samples
LM360MX	OBSOLETE	SOIC	D	8		TBD	Call TI	Call TI	0 to 70	LM 360M	
LM360MX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	SN	Level-1-260C-UNLIM	0 to 70	LM 360M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LM360MX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

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*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
I	LM360MX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0	

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)	
LM360M/NOPB	D	SOIC	8	95	495	8	4064	3.05	



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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